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1. Introduction

The sulfide-based chalcogenide glasses (ChGs) such as $\text{GeS}_2\text{-Ga}_2\text{S}_3$ glasses possess exceptional transparency and high nonlinearity, which have been widely used in multispectral imaging lenses, chemical and biological sensors, optical circuits, and planar waveguides [1-3]. However, disordered covalent-bonded networks proper to ChGs possess notable amount of

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